

SEMICONDUCTOR TM

KSE3055T

General Purpose and Switching Applications

- DC Current Gain Specified to I_C =10A
 High Current Gain-Bandwidth Product : f_T = 2MHz (Min.)



1.Base 2.Collector 3.Emitter

NPN Silicon Transistor

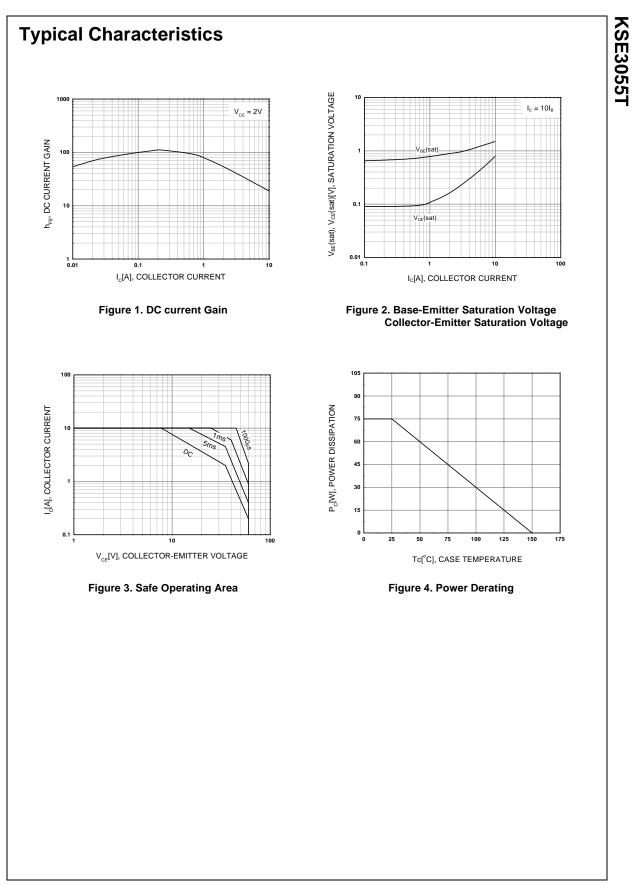
| Absolute maximum rutings r _C =25 e unless otherwise noted | Absolute Maximum | Ratings | T _C =25°C unless otherwise noted |
|--|------------------|---------|---|
|--|------------------|---------|---|

| Symbol | Parameter | Value | Units |
|---------------------------------------|--|------------|-------|
| V _{CBO} | Collector -Base Voltage | 70 | V |
| V _{CEO} | Collector-Emitter Voltage | 60 | V |
| V _{EBO} Emitter-Base Voltage | | 5 | V |
| I _C | Collector Current | 10 | Α |
| I _B | Base Current | 6 | Α |
| 0 1 10 | Collector Dissipation (T _C =25°C) | 75 | W |
| | Collector Dissipation (T _a =25°C) | 0.6 | W |
| TJ | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | - 55 ~ 150 | °C |

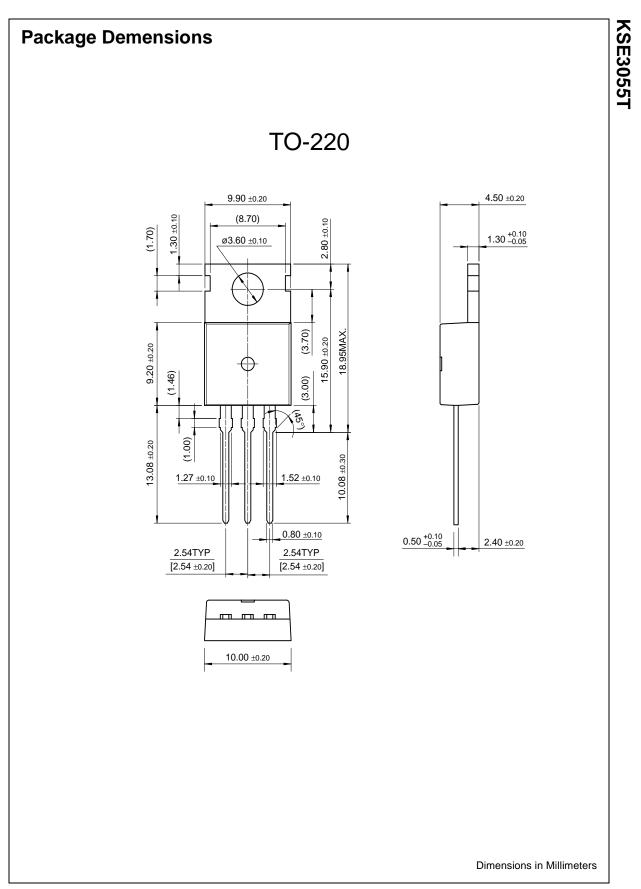
Electrical Characteristics T_C=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Max. | Units |
|--|---------------------------------------|--|---------|----------|----------|
| BV _{CEO} | Collector-Emitter Breakdown Voltage | $I_{\rm C} = 200 {\rm mA}, I_{\rm B} = 0$ | 60 | | V |
| I _{CEO} | Collector Cut-off Current | $V_{CE} = 30V, I_B = 0$ | | 700 | μΑ |
| I _{CEX1} I _{CEX2} | Collector Cut-off Current | $V_{CE} = 70V, V_{BE}(off) = -1.5V$ $V_{CE} = 70V, V_{BE}(off) = -1.5V$ @ $T_{C} = 150^{\circ}C$ | | 1 5 | mA mA |
| I _{EBO} | Emitter Cut-off Current | $V_{EB} = 5V, I_C = 0$ | | 5 | mA |
| h _{FE} | *DC Current Gain | $V_{CE} = 4V, I_C = 4A$ $V_{CE} = 4V, I_C = 10A$ | 20 5 | 100 | |
| V _{CE} (sat) | *Collector-Emitter Saturation Voltage | $I_{C} = 4A, I_{B} = 0.4A$ $I_{C} = 10A, I_{B} = 3.3A$ | | 1.1 8 | V V |
| V _{BE} (on) | *Base-Emitter On Voltage | $V_{CE} = 4V, I_C = 4A$ | | 1.8 | V |
| f _T | Current Gain Bandwidth Product | $V_{CE} = 10V, I_{C} = 500mA$ | 2 | | MHz |

* Pulse test: PW≤300µs, duty cycle≤2% Pulse



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|--------------------------|---------------------------|---|
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